

# 74LVC3G07

## Triple buffer with open-drain output

Rev. 01 — 8 June 2004

Product data sheet

## 1. General description

The 74LVC3G07 is a high-performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Input can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74LVC3G07 provides three non-inverting buffers.

The output of the device is an open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

## 2. Features

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
  - ◆ JESD8-7 (1.65 V to 1.95 V)
  - ◆ JESD8-5 (2.3 V to 2.7 V)
  - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V).
- ESD protection:
  - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
  - ◆ MM EIA/JESD22-A115-A exceeds 200 V.
- –24 mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- SOT505-2 and SOT765-1 package
- Specified from –40 °C to +85 °C and –40 °C to +125 °C.

# PHILIPS

### 3. Quick reference data

**Table 1: Quick reference data**

$GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

| Symbol                | Parameter                                  | Conditions                                                                    | Min     | Typ | Max | Unit |
|-----------------------|--------------------------------------------|-------------------------------------------------------------------------------|---------|-----|-----|------|
| $t_{PLZ}$ , $t_{PZL}$ | propagation delay<br>input nA to output nY | $V_{CC} = 1.8\text{ V}$ ;<br>$C_L = 30\text{ pF}$ ; $R_L = 1\text{ k}\Omega$  | -       | 2.9 | -   | ns   |
|                       |                                            | $V_{CC} = 2.5\text{ V}$ ;<br>$C_L = 30\text{ pF}$ ; $R_L = 500\text{ }\Omega$ | -       | 1.7 | -   | ns   |
|                       |                                            | $V_{CC} = 2.7\text{ V}$ ;<br>$C_L = 50\text{ pF}$ ; $R_L = 500\text{ }\Omega$ | -       | 2.3 | -   | ns   |
|                       |                                            | $V_{CC} = 3.3\text{ V}$ ;<br>$C_L = 50\text{ pF}$ ; $R_L = 500\text{ }\Omega$ | -       | 2.1 | -   | ns   |
|                       |                                            | $V_{CC} = 5.0\text{ V}$ ;<br>$C_L = 50\text{ pF}$ ; $R_L = 500\text{ }\Omega$ | -       | 1.5 | -   | ns   |
| $C_I$                 | input capacitance                          |                                                                               | -       | 2.5 | -   | pF   |
| $C_{PD}$              | power dissipation<br>capacitance per gate  | $V_{CC} = 3.3\text{ V}$                                                       | [1] [2] | 6.5 | -   | pF   |

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in Volts;

$N$  = total load switching outputs;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

[2] The condition is  $V_I = GND$  to  $V_{CC}$ .

### 4. Ordering information

**Table 2: Ordering information**

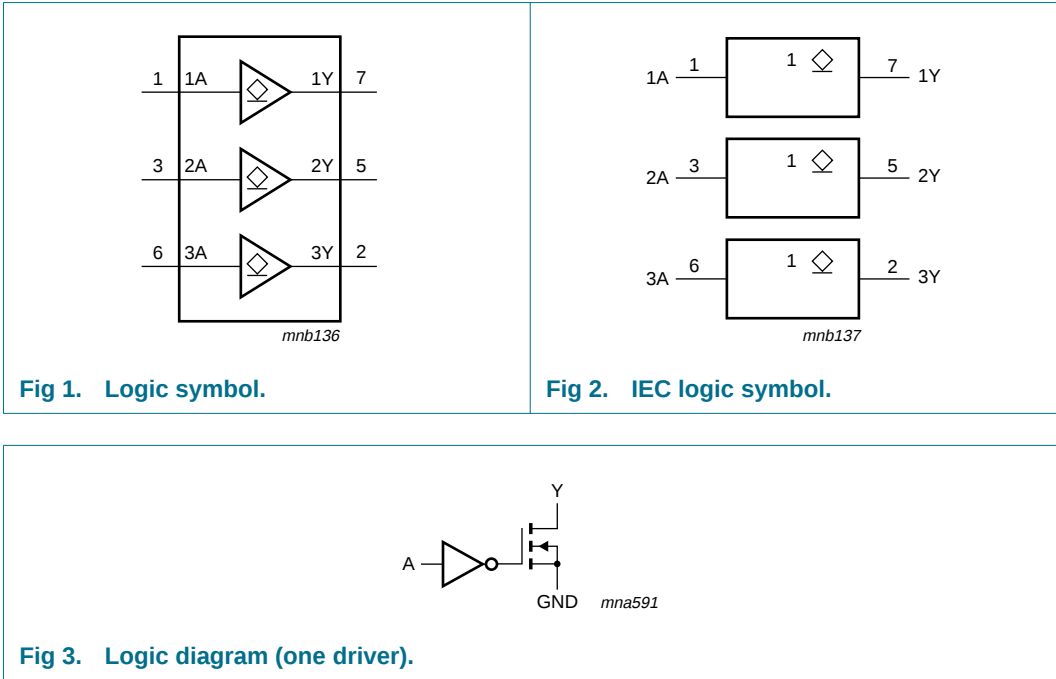
| Type number | Package                                                         |        |                                                                                         |          |
|-------------|-----------------------------------------------------------------|--------|-----------------------------------------------------------------------------------------|----------|
|             | Temperature range                                               | Name   | Description                                                                             | Version  |
| 74LVC3G07DP | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | SOT505-2 |
| 74LVC3G07DC | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm              | SOT765-1 |

### 5. Marking

**Table 3: Marking**

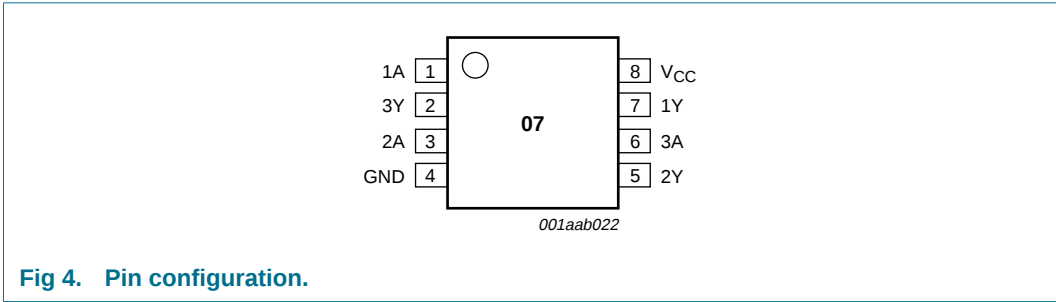
| Type number | Marking code |
|-------------|--------------|
| 74LVC3G07DP | V07          |
| 74LVC3G07DC | V07          |

6. Functional diagram



7. Pinning information

7.1 Pinning



7.2 Pin description

Table 4: Pin description

| Symbol | Pin | Description  |
|--------|-----|--------------|
| 1A     | 1   | data input   |
| 3Y     | 2   | data output  |
| 2A     | 3   | data input   |
| GND    | 4   | ground (0 V) |
| 2Y     | 5   | data output  |

Table 4: Pin description ...continued

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| 3A              | 6   | data input     |
| 1Y              | 7   | data output    |
| V <sub>CC</sub> | 8   | supply voltage |

## 8. Functional description

### 8.1 Function table

Table 5: Function table <sup>[1]</sup>

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | L      |
| H     | Z      |

- [1] H = HIGH voltage level;  
 L = LOW voltage level;  
 Z = high-impedance OFF-state.

## 9. Limiting values

Table 6: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol                             | Parameter                      | Conditions                           | Min                                | Max  | Unit |
|------------------------------------|--------------------------------|--------------------------------------|------------------------------------|------|------|
| V <sub>CC</sub>                    | supply voltage                 |                                      | -0.5                               | +6.5 | V    |
| I <sub>IK</sub>                    | input diode current            | V <sub>I</sub> < 0 V                 | -                                  | -50  | mA   |
| V <sub>I</sub>                     | input voltage                  |                                      | <sup>[1]</sup> -0.5                | +6.5 | V    |
| I <sub>OK</sub>                    | output diode current           | V <sub>O</sub> < 0 V                 | -                                  | -50  | mA   |
| V <sub>O</sub>                     | output voltage                 | active mode                          | <sup>[1]</sup> -0.5                | +6.5 | V    |
|                                    |                                | Power-down mode                      | <sup>[1]</sup> <sup>[2]</sup> -0.5 | +6.5 | V    |
| I <sub>O</sub>                     | output sink current            | V <sub>O</sub> = 0 V to 6.5 V        | -                                  | 50   | mA   |
| I <sub>CC</sub> , I <sub>GND</sub> | V <sub>CC</sub> or GND current |                                      | -                                  | ±100 | mA   |
| T <sub>stg</sub>                   | storage temperature            |                                      | -65                                | +150 | °C   |
| P <sub>tot</sub>                   | power dissipation              | T <sub>amb</sub> = -40 °C to +125 °C | -                                  | 300  | mW   |

- [1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.  
 [2] When V<sub>CC</sub> = 0 V (Power-down mode), the output voltage can be 5.5 V in normal operation.

## 10. Recommended operating conditions

Table 7: Recommended operating conditions

| Symbol     | Parameter                     | Conditions                      | Min  | Typ | Max      | Unit |
|------------|-------------------------------|---------------------------------|------|-----|----------|------|
| $V_{CC}$   | supply voltage                |                                 | 1.65 | -   | 5.5      | V    |
| $V_I$      | input voltage                 |                                 | 0    | -   | 5.5      | V    |
| $V_O$      | output voltage                | active mode                     | 0    | -   | $V_{CC}$ | V    |
|            |                               | Power-down mode; $V_{CC} = 0$ V | 0    | -   | 5.5      | V    |
| $T_{amb}$  | operating ambient temperature |                                 | -40  | -   | +125     | °C   |
| $t_r, t_f$ | input rise and fall times     | $V_{CC} = 1.65$ V to 2.7 V      | 0    | -   | 20       | ns/V |
|            |                               | $V_{CC} = 2.7$ V to 5.5 V       | 0    | -   | 10       | ns/V |

## 11. Static characteristics

Table 8: Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                           | Parameter                                   | Conditions                                                              | Min                  | Typ       | Max                  | Unit    |
|--------------------------------------------------|---------------------------------------------|-------------------------------------------------------------------------|----------------------|-----------|----------------------|---------|
| $T_{amb} = -40$ °C to +85 °C <a href="#">[1]</a> |                                             |                                                                         |                      |           |                      |         |
| $V_{IH}$                                         | HIGH-level input voltage                    | $V_{CC} = 1.65$ V to 1.95 V                                             | $0.65 \times V_{CC}$ | -         | -                    | V       |
|                                                  |                                             | $V_{CC} = 2.3$ V to 2.7 V                                               | 1.7                  | -         | -                    | V       |
|                                                  |                                             | $V_{CC} = 2.7$ V to 3.6 V                                               | 2.0                  | -         | -                    | V       |
|                                                  |                                             | $V_{CC} = 4.5$ V to 5.5 V                                               | $0.7 \times V_{CC}$  | -         | -                    | V       |
| $V_{IL}$                                         | LOW-level input voltage                     | $V_{CC} = 1.65$ V to 1.95 V                                             | -                    | -         | $0.35 \times V_{CC}$ | V       |
|                                                  |                                             | $V_{CC} = 2.3$ V to 2.7 V                                               | -                    | -         | 0.7                  | V       |
|                                                  |                                             | $V_{CC} = 2.7$ V to 3.6 V                                               | -                    | -         | 0.8                  | V       |
|                                                  |                                             | $V_{CC} = 4.5$ V to 5.5 V                                               | -                    | -         | $0.3 \times V_{CC}$  | V       |
| $V_{OL}$                                         | LOW-level output voltage                    | $V_I = V_{IH}$ or $V_{IL}$                                              |                      |           |                      |         |
|                                                  |                                             | $I_O = 100$ $\mu$ A;<br>$V_{CC} = 1.65$ V to 5.5 V                      | -                    | -         | 0.1                  | V       |
|                                                  |                                             | $I_O = 4$ mA; $V_{CC} = 1.65$ V                                         | -                    | -         | 0.45                 | V       |
|                                                  |                                             | $I_O = 8$ mA; $V_{CC} = 2.3$ V                                          | -                    | -         | 0.3                  | V       |
|                                                  |                                             | $I_O = 12$ mA; $V_{CC} = 2.7$ V                                         | -                    | -         | 0.4                  | V       |
|                                                  |                                             | $I_O = 24$ mA; $V_{CC} = 3.0$ V                                         | -                    | -         | 0.55                 | V       |
|                                                  |                                             | $I_O = 32$ mA; $V_{CC} = 4.5$ V                                         | -                    | -         | 0.55                 | V       |
| $I_{LI}$                                         | input leakage current                       | $V_I = 5.5$ V or GND;<br>$V_{CC} = 1.65$ V to 5.5 V                     | -                    | $\pm 0.1$ | $\pm 5$              | $\mu$ A |
| $I_{OZ}$                                         | 3-state output OFF-state current            | $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND;<br>$V_{CC} = 5.5$ V | -                    | $\pm 0.1$ | $\pm 10$             | $\mu$ A |
| $I_{off}$                                        | power-off leakage current                   | $V_I$ or $V_O = 5.5$ V; $V_{CC} = 0$ V                                  | -                    | $\pm 0.1$ | $\pm 10$             | $\mu$ A |
| $I_{CC}$                                         | quiescent supply current                    | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5$ V                 | -                    | 0.1       | 10                   | $\mu$ A |
| $\Delta I_{CC}$                                  | additional quiescent supply current per pin | $V_I = V_{CC} - 0.6$ V; $I_O = 0$ A;<br>$V_{CC} = 2.3$ V to 5.5 V       | -                    | 5         | 500                  | $\mu$ A |

**Table 8:** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                                                  | Parameter                                   | Conditions                                                                             | Min                  | Typ | Max                  | Unit          |
|-------------------------------------------------------------------------|---------------------------------------------|----------------------------------------------------------------------------------------|----------------------|-----|----------------------|---------------|
| $C_I$                                                                   | input capacitance                           |                                                                                        | -                    | 2.5 | -                    | pF            |
| $T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}$ |                                             |                                                                                        |                      |     |                      |               |
| $V_{IH}$                                                                | HIGH-level input voltage                    | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$                                              | $0.65 \times V_{CC}$ | -   | -                    | V             |
|                                                                         |                                             | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$                                                | 1.7                  | -   | -                    | V             |
|                                                                         |                                             | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$                                                | 2.0                  | -   | -                    | V             |
|                                                                         |                                             | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                                                | $0.7 \times V_{CC}$  | -   | -                    | V             |
| $V_{IL}$                                                                | LOW-level input voltage                     | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$                                              | -                    | -   | $0.35 \times V_{CC}$ | V             |
|                                                                         |                                             | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$                                                | -                    | -   | 0.7                  | V             |
|                                                                         |                                             | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$                                                | -                    | -   | 0.8                  | V             |
|                                                                         |                                             | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                                                | -                    | -   | $0.3 \times V_{CC}$  | V             |
| $V_{OL}$                                                                | LOW-level output voltage                    | $V_I = V_{IH}\text{ or }V_{IL}$                                                        |                      |     |                      |               |
|                                                                         |                                             | $I_O = 100\text{ }\mu\text{A}; V_{CC} = 1.65\text{ V to }5.5\text{ V}$                 | -                    | -   | 0.1                  | V             |
|                                                                         |                                             | $I_O = 4\text{ mA}; V_{CC} = 1.65\text{ V}$                                            | -                    | -   | 0.70                 | V             |
|                                                                         |                                             | $I_O = 8\text{ mA}; V_{CC} = 2.3\text{ V}$                                             | -                    | -   | 0.45                 | V             |
|                                                                         |                                             | $I_O = 12\text{ mA}; V_{CC} = 2.7\text{ V}$                                            | -                    | -   | 0.60                 | V             |
|                                                                         |                                             | $I_O = 24\text{ mA}; V_{CC} = 3.0\text{ V}$                                            | -                    | -   | 0.80                 | V             |
|                                                                         |                                             | $I_O = 32\text{ mA}; V_{CC} = 4.5\text{ V}$                                            | -                    | -   | 0.80                 | V             |
| $I_{LI}$                                                                | input leakage current                       | $V_I = 5.5\text{ V or GND}; V_{CC} = 1.65\text{ V to }5.5\text{ V}$                    | -                    | -   | $\pm 20$             | $\mu\text{A}$ |
| $I_{OZ}$                                                                | 3-state output OFF-state current            | $V_I = V_{IH}\text{ or }V_{IL}; V_O = V_{CC}\text{ or GND}; V_{CC} = 5.5\text{ V}$     | -                    | -   | $\pm 10$             | $\mu\text{A}$ |
| $I_{off}$                                                               | power OFF leakage current                   | $V_I\text{ or }V_O = 5.5\text{ V}; V_{CC} = 0\text{ V}$                                | -                    | -   | $\pm 20$             | $\mu\text{A}$ |
| $I_{CC}$                                                                | quiescent supply current                    | $V_I = V_{CC}\text{ or GND}; I_O = 0\text{ A}; V_{CC} = 5.5\text{ V}$                  | -                    | -   | 40                   | $\mu\text{A}$ |
| $\Delta I_{CC}$                                                         | additional quiescent supply current per pin | $V_I = V_{CC} - 0.6\text{ V}; I_O = 0\text{ A}; V_{CC} = 2.3\text{ V to }5.5\text{ V}$ | -                    | -   | 5000                 | $\mu\text{A}$ |

[1] All typical values are measured at nominal  $V_{CC}$  and  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

## 12. Dynamic characteristics

**Table 9:** Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                                                     | Parameter                               | Conditions                                         | Min | Typ | Max | Unit |
|----------------------------------------------------------------------------|-----------------------------------------|----------------------------------------------------|-----|-----|-----|------|
| $T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}$ [1] |                                         |                                                    |     |     |     |      |
| $t_{PLZ}, t_{PZL}$                                                         | propagation delay input nA to output nY | see <a href="#">Figure 5</a> and <a href="#">6</a> |     |     |     |      |
|                                                                            |                                         | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$          | 1.0 | 2.9 | 6.7 | ns   |
|                                                                            |                                         | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$            | 0.5 | 1.7 | 4.3 | ns   |
|                                                                            |                                         | $V_{CC} = 2.7\text{ V}$                            | 1.0 | 2.3 | 4.2 | ns   |
|                                                                            |                                         | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$            | 0.5 | 2.1 | 3.7 | ns   |
|                                                                            |                                         | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$            | 0.5 | 1.5 | 2.9 | ns   |

Table 9: Dynamic characteristics ...continued  
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                                  | Conditions                                         | Min                                     | Typ | Max | Unit |
|--------------------------------------------|--------------------------------------------|----------------------------------------------------|-----------------------------------------|-----|-----|------|
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                                            |                                                    |                                         |     |     |      |
| t <sub>PLZ</sub> , t <sub>PZL</sub>        | propagation delay<br>input nA to output nY | see <a href="#">Figure 5</a> and <a href="#">6</a> |                                         |     |     |      |
|                                            |                                            | V <sub>CC</sub> = 1.65 V to 1.95 V                 | 1.0                                     | -   | 8.4 | ns   |
|                                            |                                            | V <sub>CC</sub> = 2.3 V to 2.7 V                   | 0.5                                     | -   | 5.5 | ns   |
|                                            |                                            | V <sub>CC</sub> = 2.7 V                            | 1.0                                     | -   | 5.3 | ns   |
|                                            |                                            | V <sub>CC</sub> = 3.0 V to 3.6 V                   | 0.5                                     | -   | 4.7 | ns   |
|                                            |                                            | V <sub>CC</sub> = 4.5 V to 5.5 V                   | 0.5                                     | -   | 3.7 | ns   |
| C <sub>PD</sub>                            | power dissipation<br>capacitance per gate  | V <sub>CC</sub> = 3.3 V                            | <a href="#">[2]</a> <a href="#">[3]</a> | 6.5 | -   | pF   |

- [1] All typical values are measured at nominal V<sub>CC</sub> and T<sub>amb</sub> = 25 °C.
- [2] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>i</sub> × N + Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) where:  
f<sub>i</sub> = input frequency in MHz;  
f<sub>o</sub> = output frequency in MHz;  
C<sub>L</sub> = output load capacitance in pF;  
V<sub>CC</sub> = supply voltage in Volts;  
N = total load switching outputs;  
Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of outputs.
- [3] The condition is V<sub>I</sub> = GND to V<sub>CC</sub>.

13. Waveforms

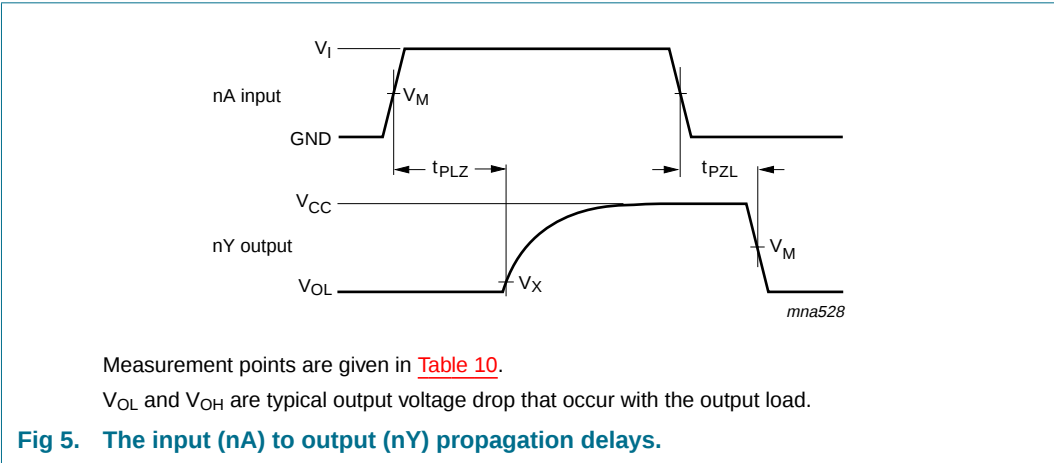


Table 10: Measurement points

| Supply voltage   | Input                 |                 | Output                |                          |
|------------------|-----------------------|-----------------|-----------------------|--------------------------|
| V <sub>CC</sub>  | V <sub>M</sub>        | V <sub>I</sub>  | V <sub>M</sub>        | V <sub>X</sub>           |
| 1.65 V to 1.95 V | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>OL</sub> + 0.15 V |
| 2.3 V to 2.7 V   | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>OL</sub> + 0.15 V |
| 2.7 V            | 1.5 V                 | 2.7 V           | 1.5 V                 | V <sub>OL</sub> + 0.3 V  |
| 3.0 V to 3.6 V   | 1.5 V                 | 2.7 V           | 1.5 V                 | V <sub>OL</sub> + 0.3 V  |
| 4.5 V to 5.5 V   | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>OL</sub> + 0.3 V  |

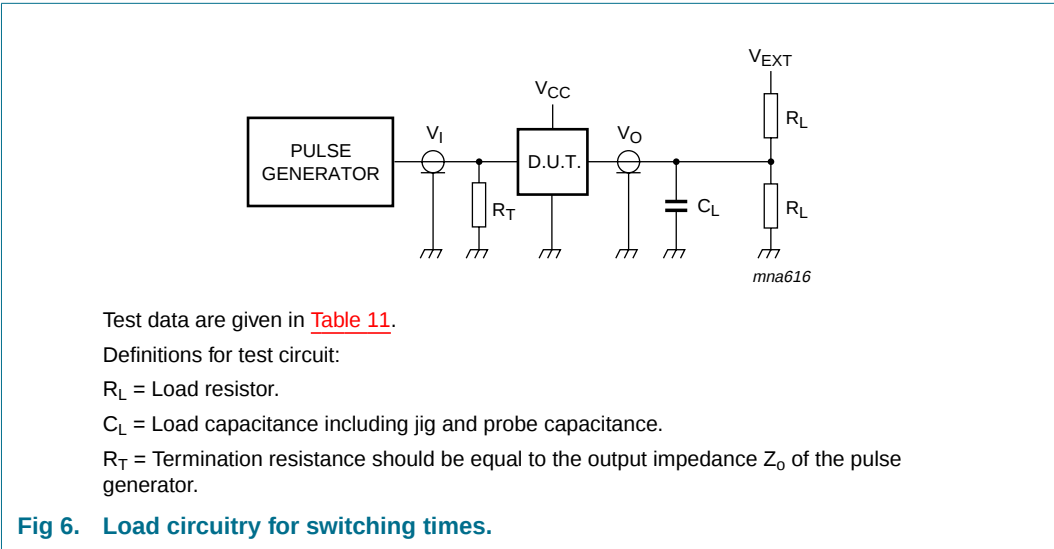


Table 11: Test data

| Supply voltage   | Input           |                                 | Load           |                | V <sub>EXT</sub>                    |
|------------------|-----------------|---------------------------------|----------------|----------------|-------------------------------------|
| V <sub>CC</sub>  | V <sub>I</sub>  | t <sub>r</sub> = t <sub>f</sub> | C <sub>L</sub> | R <sub>L</sub> | t <sub>pZL</sub> , t <sub>pLZ</sub> |
| 1.65 V to 1.95 V | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF          | 1 kΩ           | 2 × V <sub>CC</sub>                 |
| 2.3 V to 2.7 V   | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF          | 500 Ω          | 2 × V <sub>CC</sub>                 |
| 2.7 V            | 2.7 V           | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | 6 V                                 |
| 3.0 V to 3.6 V   | 2.7 V           | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | 6 V                                 |
| 4.5 V to 5.5 V   | V <sub>CC</sub> | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | 2 × V <sub>CC</sub>                 |

14. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm    SOT505-2

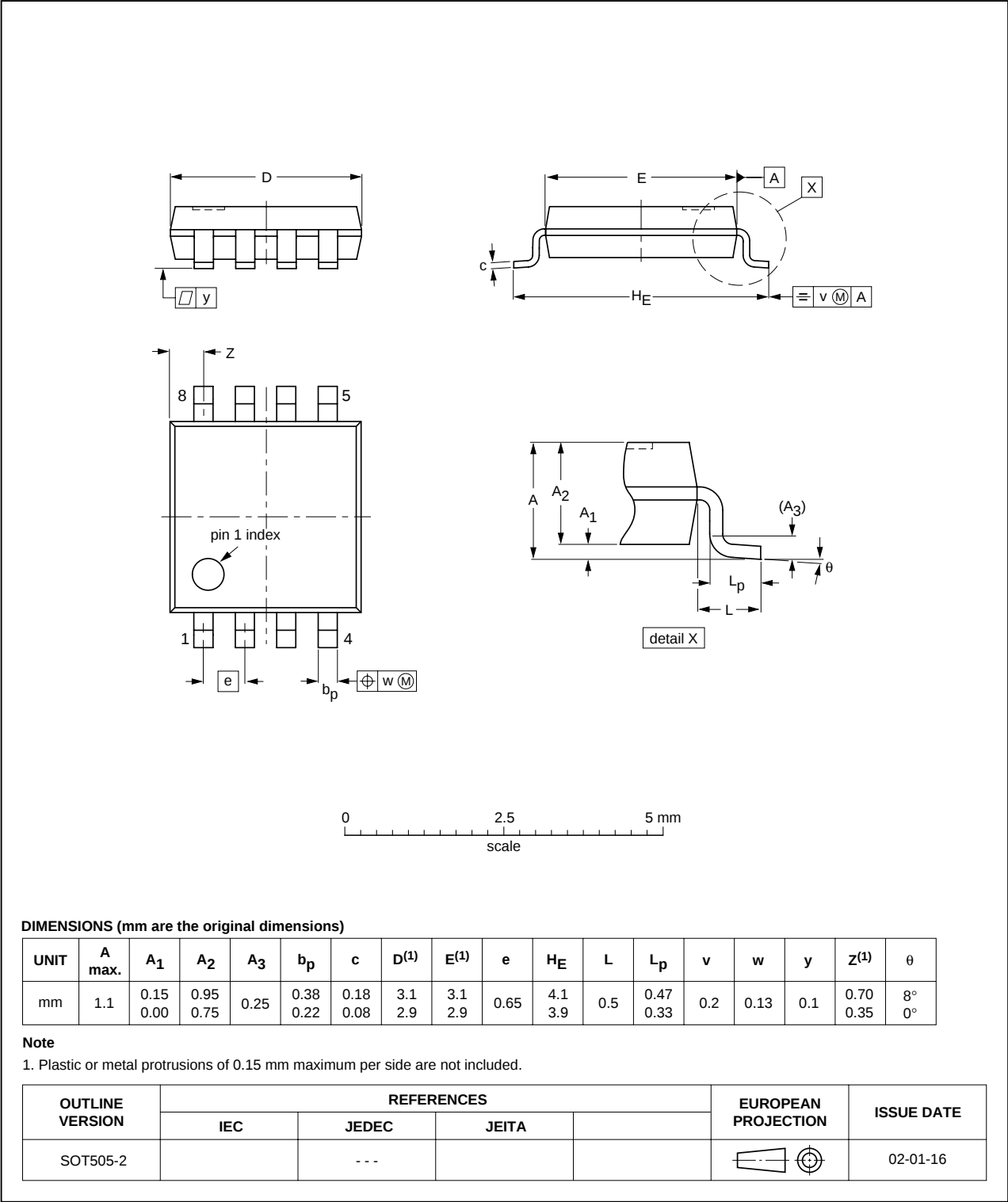
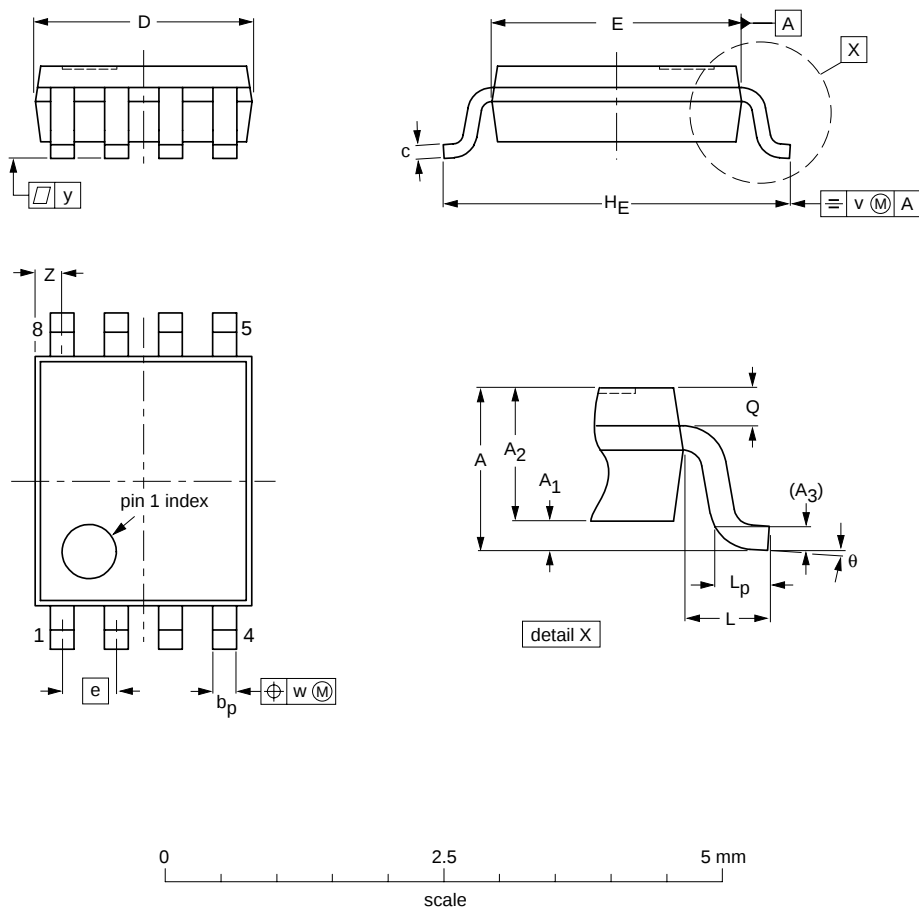


Fig 7. Package outline TSSOP8.

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



DIMENSIONS (mm are the original dimensions)

| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | b <sub>p</sub> | c            | D <sup>(1)</sup> | E <sup>(2)</sup> | e   | H <sub>E</sub> | L   | L <sub>p</sub> | Q            | v   | w    | y   | z <sup>(1)</sup> | θ        |
|------|-----------|----------------|----------------|----------------|----------------|--------------|------------------|------------------|-----|----------------|-----|----------------|--------------|-----|------|-----|------------------|----------|
| mm   | 1         | 0.15<br>0.00   | 0.85<br>0.60   | 0.12           | 0.27<br>0.17   | 0.23<br>0.08 | 2.1<br>1.9       | 2.4<br>2.2       | 0.5 | 3.2<br>3.0     | 0.4 | 0.40<br>0.15   | 0.21<br>0.19 | 0.2 | 0.13 | 0.1 | 0.4<br>0.1       | 8°<br>0° |

- Notes
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
  2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

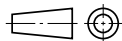
| OUTLINE<br>VERSION | REFERENCES |        |       |  | EUROPEAN<br>PROJECTION                                                                | ISSUE DATE |
|--------------------|------------|--------|-------|--|---------------------------------------------------------------------------------------|------------|
|                    | IEC        | JEDEC  | JEITA |  |                                                                                       |            |
| SOT765-1           |            | MO-187 |       |  |  | 02-06-07   |

Fig 8. Package outline VSSOP.

15. Revision history

Table 12: Revision history

| Document ID | Release date | Data sheet status | Change notice | Order number   | Supersedes |
|-------------|--------------|-------------------|---------------|----------------|------------|
| 74LVC3G07_1 | 20040608     | Product data      | -             | 9397 750 13267 | -          |

## 16. Data sheet status

| Level | Data sheet status <sup>[1]</sup> | Product status <sup>[2]</sup> <sup>[3]</sup> | Definition                                                                                                                                                                                                                                                                                     |
|-------|----------------------------------|----------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| I     | Objective data                   | Development                                  | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.                                                                                                    |
| II    | Preliminary data                 | Qualification                                | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.             |
| III   | Product data                     | Production                                   | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

## 17. Definitions

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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